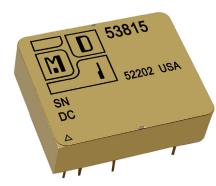
HYBRID SOLID STATE RELAY



Features:

- High Voltage/Low Resistance
- Single Pole, Single Throw Available in Form A or Form B
- Wide Band Gap Semiconductors for low Resistance
- Magnetically Coupled Command for fast response
- No Optocoupler, no optocoupler issues
- Selectable Continuous or Mag Latch
 Function
- Logic Level Drive
- Rugged Hermetic Package

Specifications:

Bias Input Voltage 4.7 to 5.3 VDC Bias input current 30 mA typical, 50 mA maximum

Command input 1 mA compatible with TTL logic levels

Input/output and all pins to case isolation 1kV

Power Dissipation 10 watts at maximum rated case temperature

Case temperature range:

Operating -55°C to +85°C (M grade) Operating -55°C to +125°C (E grade) Operating -40°C to +85°C (Industrial Grade)

Storage -65°C to +150°C

Weight 32 grams typical For continuous operation, connect 5 VDC bias from pin 1 to bias ground pin 2.

Ground pin 3 and apply +5 VDC to pin 4 to energize the SSR.

For latch operation, leave pin 3 open, connect 5 VDC bias from pin 1 to bias ground pin 2.

- To energize apply +5 VDC pulse, 25 microseconds minimum to pin 5.
- To de-energize apply +5 VDC pulse, 25 microseconds minimum to pin 4.

Power Dissipation:

Total steady state power dissipation of the model 3814 and 3815 is limited to 10 watts provided the baseplate temperature is limited to the rated temperature.



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MODELS 3814/3815

Model 3815 is a SPST form B (normally closed when de-energized) SSR. Model 3814 is a SPST form A (normally open when de-energized) SSR.

Both types use Wide Bandgap power semiconductors for high performance, are magnetically coupled and can be user configured for continuous or pulse latching.

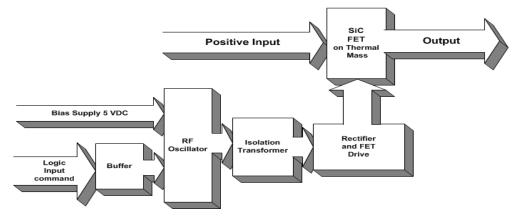
Wide band gap (WBG) semiconductors, such as GaN (Gallium Nitride) and SiC (Silicon Carbide) provide an order of magnitude improvement in SSR voltage drop compared to SSRs using Silicon based power devices.

Also, WBG semiconductors of a given dimension can withstand higher electric fields than Silicon semiconductors, the physical dimensions of these WBG parts are considerably smaller than their Silicon competitors. The result of WBG is much lower channel resistances and reduced drive requirements.

Many SSR manufacturers drive their SSR power device with opto couplers consisting of an LED emitter driving a multi-diode photo-voltaic stack.

Both the LED's and photovoltaic stacks are challenged by a radiation environment. A second disadvantage of opto coupled drive is slow turn on and off response.

MDI replaces the optocoupler function with a tiny, transformer isolated RF drive signal. This solves the opto coupler problems and gives faster, more temperature stable operation, as well as excellent radiation resistance.



300V/3A Solid State Relay Model 3815 Form B Model 3814 Form A

PARAMETER	CONDITION	MIN	TYP	MAX		
Contact Ratng V	Max	-	_	500V		
Contact Rating I	Max	—	—	ЗA		
Contact Resistance, 25°C	Energized	-	0.2 Ω	0.25 Ω		
Contact Resistance, 125°C	Energized	—	0.35 Ω	0.45 Ω		
Leakage Current, 600V, 25°C	Off	_	_	60µA		
Leakage Current, 600V, 125°C	Off	—	—	100µA		
Bias Voltage	_	4.7V	5.0V	5.3V		
Bias Current	_	_	30mA	50mA		
Command/Pulse Inputs on	_	3.0V	5.0V	6.0V		
Command/Pulse Inputs off	_	0V	0.5V	1.0V		
Command Current	_	0.1mA	0.8mA	2.0mA		
Delay Time, energized	_	_	12µS	30µS		
Delay Time, de-energized	_	_	20µS	40µS		
Energize Time, dynamic	-	—	12µS	30µS		
De-edergize time, dynamic	-	-	5µS	20µS		

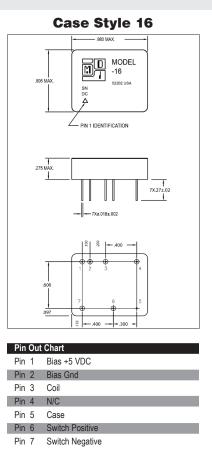
For Heat Removal and Mounting Recommendations See MDI application notes on mounting considerations for DC-DC Converters

Beleased 2019-04-xx

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3814/3815

HYBRID SOLID STATE RELAY



Model No.	Case Style	Pin Count	Mounting
3814/3815 -	16	7	Seam Weld Flangeless PCB Mount

GRADE LEVELS:

Please specify grade level for your application. EU grade units will be shipped if no option is specified.

EU	Engineering Uint	1	Industrial -55°C to +85°C
Μ	Military -55°C to +85°C	E	Military -55°C to +125°C



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